

Features

- Pin- and function-compatible with CY7C1020CV33
- Temperature Ranges
 - Commercial: 0 °C to 70 °C
 - Industrial: -40 °C to 85 °C
 - Automotive: -40 °C to 125 °C
- High speed
 - $t_{AA} = 10 \text{ ns}$
- CMOS for optimum speed/power
- Low active power
 - 325 mW (max)
- Automatic power-down when deselected
- Independent control of upper and lower bits
- Available in Pb-free and non Pb-free 44-pin TSOP II package

Functional Description

The CY7C1020CV33 is a high-performance CMOS static RAM organized as 32,768 words by 16 bits. This device has an automatic power-down feature that significantly reduces power consumption when deselected.

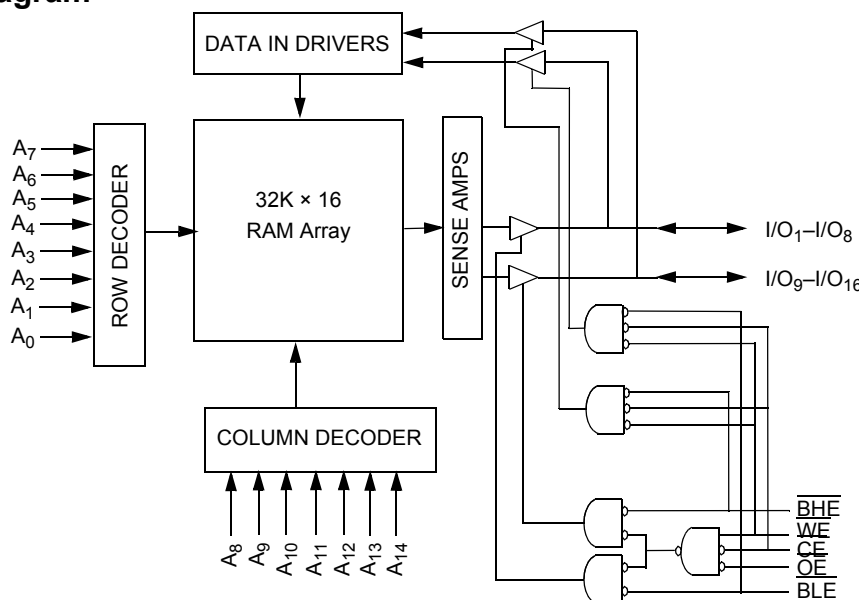
Writing to the device is accomplished by taking Chip Enable ($\overline{CE}$) and Write Enable (WE) inputs LOW. If Byte Low Enable (BLE) is LOW, then data from I/O pins (I/O₁ through I/O₈), is written into the location specified on the address pins (A₀ through A₁₄). If Byte High Enable (BHE) is LOW, then data from I/O pins (I/O₉ through I/O₁₆) is written into the location specified on the address pins (A₀ through A₁₄).

Reading from the device is accomplished by taking Chip Enable ($\overline{CE}$) and Output Enable ($\overline{OE}$) LOW while forcing the Write Enable (WE) HIGH. If Byte Low Enable (BLE) is LOW, then data from the memory location specified by the address pins will appear on I/O₁ to I/O₈. If Byte High Enable (BHE) is LOW, then data from memory will appear on I/O₉ to I/O₁₆. See the truth table at the back of this data sheet for a complete description of read and write modes.

The input/output pins (I/O₁ through I/O₁₆) are placed in a high-impedance state when the device is deselected ($\overline{CE}$ HIGH), the outputs are disabled ($\overline{OE}$ HIGH), the BHE and BLE are disabled (BHE, BLE HIGH), or during a write operation ($\overline{CE}$ LOW, and WE LOW).

The CY7C1020CV33 is available in standard 44-pin TSOP Type II package.

Logic Block Diagram



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Selection Guide

		-10	-12	-15	Unit
Maximum Access Time		10	12	15	ns
Maximum Operating Current	Commercial/Industrial	90	85	80	mA
	Automotive	—	—	85	mA
Maximum CMOS Standby Current	Commercial/Industrial	5	5	5	mA
	Automotive	—	—	10	mA

Pin Configuration ^[1]

TSOP II
Top View

NC	1	44	A ₅
A ₃	2	43	A ₆
A ₂	3	42	A ₇
A ₁	4	41	OE
A ₀	5	40	BHE
CE	6	39	BLE
I/O ₁	7	38	I/O ₁₆
I/O ₂	8	37	I/O ₁₅
I/O ₃	9	36	I/O ₁₄
I/O ₄	10	35	I/O ₁₃
V _{CC}	11	34	V _{SS}
V _{SS}	12	33	V _{CC}
I/O ₅	13	32	I/O ₁₂
I/O ₆	14	31	I/O ₁₁
I/O ₇	15	30	I/O ₁₀
I/O ₈	16	29	I/O ₉
WE	17	28	NC
A ₄	18	27	A ₈
A ₁₄	19	26	A ₉
A ₁₃	20	25	A ₁₀
A ₁₂	21	24	A ₁₁
NC	22	23	NC

Note

1. NC pins are not connected on the die.

Pin Definitions

Pin Name	TSOP - Pin Number	I/O Type	Description
A ₀ –A ₁₄	5, 4, 3, 2, 18, 44, 43, 42, 27, 26, 25, 24, 21, 20, 19	Input	Address Inputs used to select one of the address locations.
I/O ₁ –I/O ₁₆	7-10, 13-16, 29-32, 35-38	Input/Output	Bidirectional Data I/O lines. Used as input or output lines depending on operation.
NC	1, 22, 23, 28	No Connect	No Connects. Not connected to the die.
$\overline{\text{WE}}$	17	Input/Control	Write Enable Input, active LOW. When selected LOW, a Write is conducted. When deselected HIGH, a Read is conducted.
$\overline{\text{CE}}$	6	Input/Control	Chip Enable Input, active LOW. When LOW, selects the chip. When HIGH, deselects the chip.
$\overline{\text{BHE}}, \overline{\text{BLE}}$	40, 39	Input/Control	Byte Write Select Inputs, active LOW. $\overline{\text{BHE}}$ controls I/O ₁₆ –I/O ₉ , $\overline{\text{BLE}}$ controls I/O ₈ –I/O ₁ .
$\overline{\text{OE}}$	41	Input/Control	Output Enable, active LOW. Controls the direction of the I/O pins. When LOW, the I/O pins are allowed to behave as outputs. When deasserted HIGH, I/O pins are tri-stated, and act as input data pins.
V _{SS}	12, 34	Ground	Ground for the device. Should be connected to ground of the system.
V _{CC}	11, 33	Power Supply	Power Supply inputs to the device.

Maximum Ratings

Exceeding maximum ratings may shorten the useful life of the device. User guidelines are not tested.

Storage temperature -65 °C to +150 °C

Ambient temperature with power applied -55 °C to +125 °C

Supply voltage on V_{CC} to relative GND^[2] -0.5 V to +4.6 V

DC voltage applied to outputs in high Z State^[2] -0.5 V to $V_{CC} + 0.5$ V

DC input voltage^[2] -0.5 V to $V_{CC} + 0.5$ V

Current into outputs (LOW) 20 mA

Static discharge voltage > 2001 V (per MIL-STD-883, method 3015)

Latch-up current > 200 mA

Operating Range

Range	Ambient Temperature	V_{CC}
Commercial	0 °C to +70 °C	3.3 V ± 10%
Industrial	-40 °C to +85 °C	3.3 V ± 10%
Automotive	-40 °C to +125 °C	3.3 V ± 10%

Electrical Characteristics

Over the Operating Range

Parameter	Description	Test Conditions		-10		-12		-15		Unit
				Min	Max	Min	Max	Min	Max	
V _{OH}	Output HIGH voltage	V _{CC} = Min, I _{OH} = -4.0 mA		2.4	—	2.4	—	2.4	—	V
V _{OL}	Output LOW voltage	V _{CC} = Min, I _{OL} = 8.0 mA		—	0.4	—	0.4	—	0.4	V
V _{IH}	Input HIGH voltage			2.0	V _{CC} + 0.3	2.0	V _{CC} + 0.3	2.0	V _{CC} + 0.3	V
V _{IL}	Input LOW voltage ^[2]			-0.3	0.8	-0.3	0.8	-0.3	0.8	V
I _{IX}	Input leakage current	GND ≤ V _I ≤ V _{CC}	Commercial/ Industrial	-1	+1	-1	+1	-1	+1	μA
			Automotive	—	—	—	—	-20	+20	μA
I _{OZ}	Output leakage current	GND ≤ V _I ≤ V _{CC} , Output Disabled	Commercial/ Industrial	-1	+1	-1	+1	-1	+1	μA
			Automotive	—	—	—	—	-20	+20	μA
I _{CC}	V _{CC} operating supply current	V _{CC} = Max, I _{OUT} = 0 mA, f = f _{MAX} = 1/t _{RC}	Commercial/ Industrial	—	90	—	85	—	80	mA
			Automotive	—	—	—	—	—	85	mA
I _{SB1}	Automatic CE power-down current —TTL Inputs	Max V _{CC} , CE ≥ V _{IH} , V _{IN} ≥ V _{IH} or V _{IN} ≤ V _{IL} , f = f _{MAX}	Commercial/ Industrial	—	15	—	15	—	15	mA
			Automotive	—	—	—	—	—	20	mA
I _{SB2}	Automatic CE power-down current —CMOS inputs	Max V _{CC} , CE ≥ V _{CC} - 0.3 V, V _{IN} ≥ V _{CC} - 0.3 V, or V _{IN} ≤ 0.3 V, f = 0	Commercial/ Industrial	—	5	—	5	—	5	mA
			Automotive	—	—	—	—	—	10	mA

Capacitance^[3]

Parameter	Description	Test Conditions	Max	Unit
C_{IN}	Input capacitance	$T_A = 25 \text{ °C}, f = 1 \text{ MHz}, V_{CC} = 3.3 \text{ V}$	8	pF
C_{OUT}	Output capacitance		8	pF

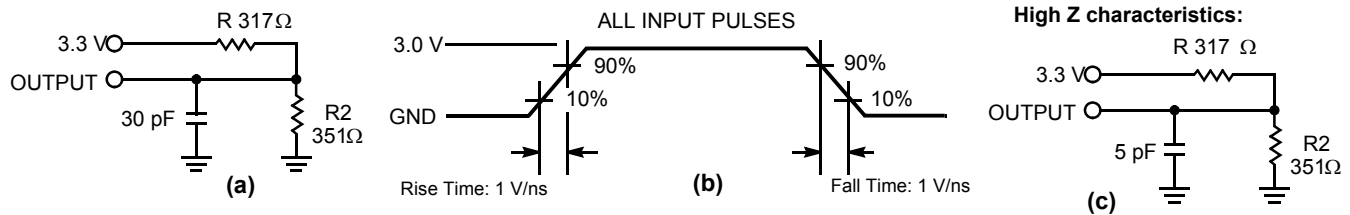
Thermal Resistance^[3]

Parameter	Description	Test Conditions	44-pin TSOP-II	Unit
Θ_{JA}	Thermal resistance (Junction to Ambient)	Test conditions follow standard test methods and procedures for measuring thermal impedance, per EIA/JESD51.	76.92	°C/W
Θ_{JC}	Thermal resistance (Junction to Case)		15.86	°C/W

Notes

- $V_{IL}(\text{min}) = -2.0 \text{ V}$ and $V_{IH}(\text{max}) = V_{CC} + 0.5 \text{ V}$ for pulse durations of less than 20 ns.
- Tested initially and after any design or process changes that may affect these parameters.

AC Test Loads and Waveforms^[4]



Switching Characteristics

Over the Operating Range^[4]

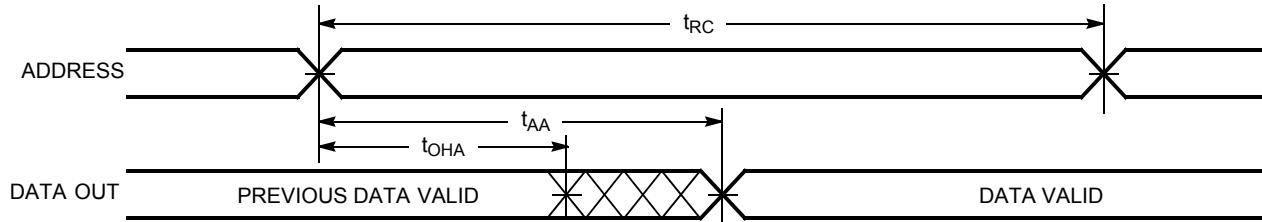
Parameter	Description	−10		−12		−15		Unit
		Min	Max	Min	Max	Min	Max	
Read Cycle								
t _{RC}	Read cycle time	10	–	12	–	15	–	ns
t _{AA}	Address to data valid	–	10	–	12	–	15	ns
t _{OHA}	Data hold from address change	3	–	3	–	3	–	ns
t _{ACE}	$\overline{CE}$ LOW to data valid	–	10	–	12	–	15	ns
t _{DOE}	$\overline{OE}$ LOW to data valid	–	5	–	6	–	7	ns
t _{LZOE}	$\overline{OE}$ LOW to low Z ^[5]	0	–	0	–	0	–	ns
t _{HZOE}	$\overline{OE}$ HIGH to high Z ^[5, 6]	–	5	–	6	–	7	ns
t _{LZCE}	$\overline{CE}$ LOW to low Z ^[5]	3	–	3	–	3	–	ns
t _{HZCE}	$\overline{CE}$ HIGH to high Z ^[5, 6]	–	5	–	6	–	7	ns
t _{PU} ^[7]	$\overline{CE}$ LOW to power-up	0	–	0	–	0	–	ns
t _{PD} ^[7]	$\overline{CE}$ HIGH to power-down	–	10	–	12	–	15	ns
t _{DBE}	Byte enable to data valid	–	5	–	6	–	7	ns
t _{LZBE}	Byte enable to low Z	0	–	0	–	0	–	ns
t _{HZBE}	Byte disable to high Z	–	5	–	6	–	7	ns
Write Cycle ^[8]								
t _{WC}	Write cycle time	10	–	12	–	15	–	ns
t _{SCE}	$\overline{CE}$ LOW to write end	8	–	9	–	10	–	ns
t _{AW}	Address set-up to write end	7	–	8	–	10	–	ns
t _{HA}	Address hold from write end	0	–	0	–	0	–	ns
t _{SA}	Address set-up to write start	0	–	0	–	0	–	ns
t _{PWE}	$\overline{WE}$ pulse width	7	–	8	–	10	–	ns
t _{SD}	Data set-up to write end	5	–	6	–	8	–	ns
t _{HD}	Data hold from write end	0	–	0	–	0	–	ns
t _{LZWE}	$\overline{WE}$ HIGH to low Z ^[5]	3	–	3	–	3	–	ns
t _{HZWE}	$\overline{WE}$ LOW to high Z ^[5, 6]	–	5	–	6	–	7	ns
t _{BW}	Byte enable to end of write	7	–	8	–	9	–	ns

Notes

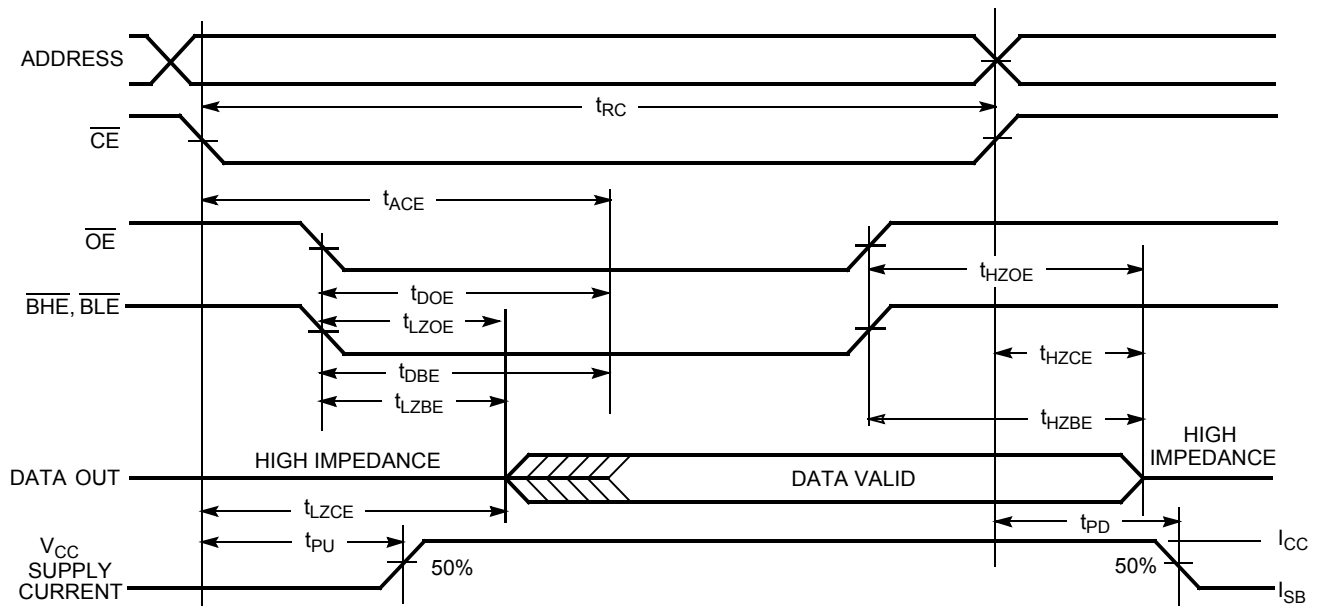
- Test conditions assume signal transition time of 3 ns or less, timing reference levels of 1.5 V, input pulse levels of 0 to 3.0 V.
- At any given temperature and voltage condition, t_{HZCE} is less than t_{LZCE} , t_{HZOE} is less than t_{LZOE} , and t_{HZWE} is less than t_{LZWE} for any given device.
- t_{HZOE} , t_{HZBE} , t_{HZCE} , and t_{HZWE} are specified with a load capacitance of 5 pF as in part (c) of AC Test Loads. Transition is measured ± 500 mV from steady-state voltage.
- This parameter is guaranteed by design and is not tested.
- The internal Write time of the memory is defined by the overlap of $\overline{CE}$ LOW, $\overline{WE}$ LOW and $\overline{BHE}/\overline{BLE}$ LOW. $\overline{CE}$, $\overline{WE}$ and $\overline{BHE}/\overline{BLE}$ must be LOW to initiate a Write, and the transition of these signals can terminate the Write. The input data set-up and hold timing should be referenced to the leading edge of the signal that terminates the Write.

Switching Waveforms

Read Cycle No. 1^[9, 10]



Read Cycle No. 2 ($\overline{OE}$ Controlled)^[10, 11]

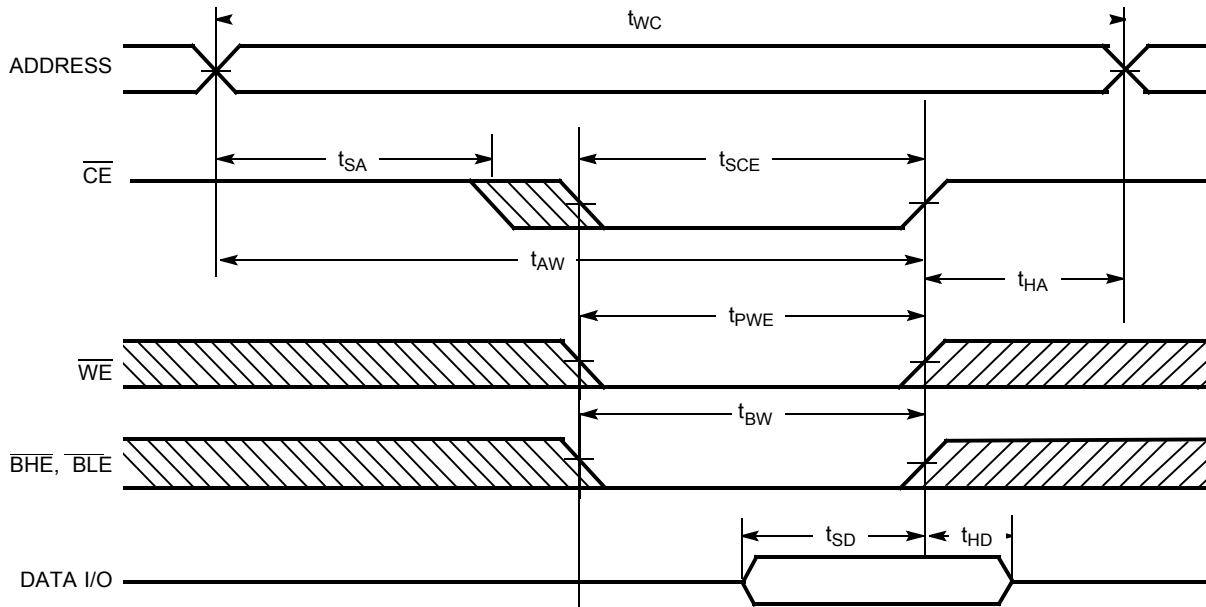


Notes

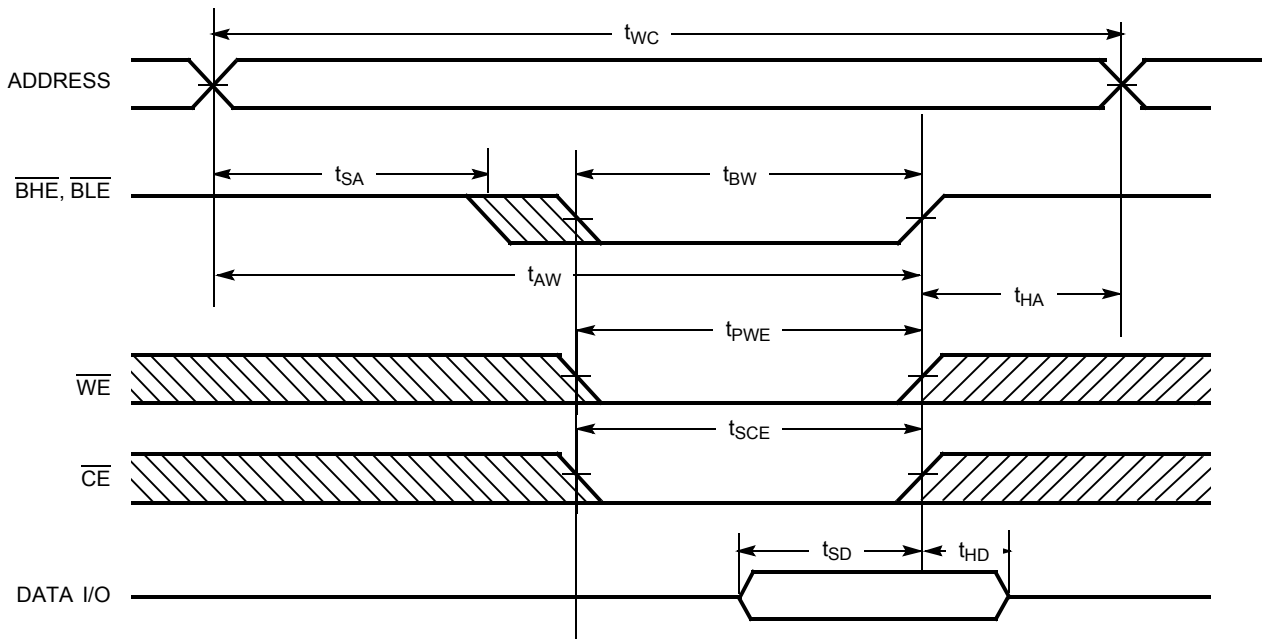
9. Device is continuously selected. $\overline{OE}$, $\overline{CE}$, $\overline{BHE}$ and/or $\overline{BLE}$ = V_{IL} .
10. $\overline{WE}$ is HIGH for Read cycle.
11. Address valid prior to or coincident with $\overline{CE}$ transition LOW.

Switching Waveforms *(continued)*

Write Cycle No. 1 ($\overline{\text{CE}}$ Controlled)^[12, 13]



Write Cycle No. 2 ($\overline{\text{BLE}}$ or $\overline{\text{BHE}}$ Controlled)

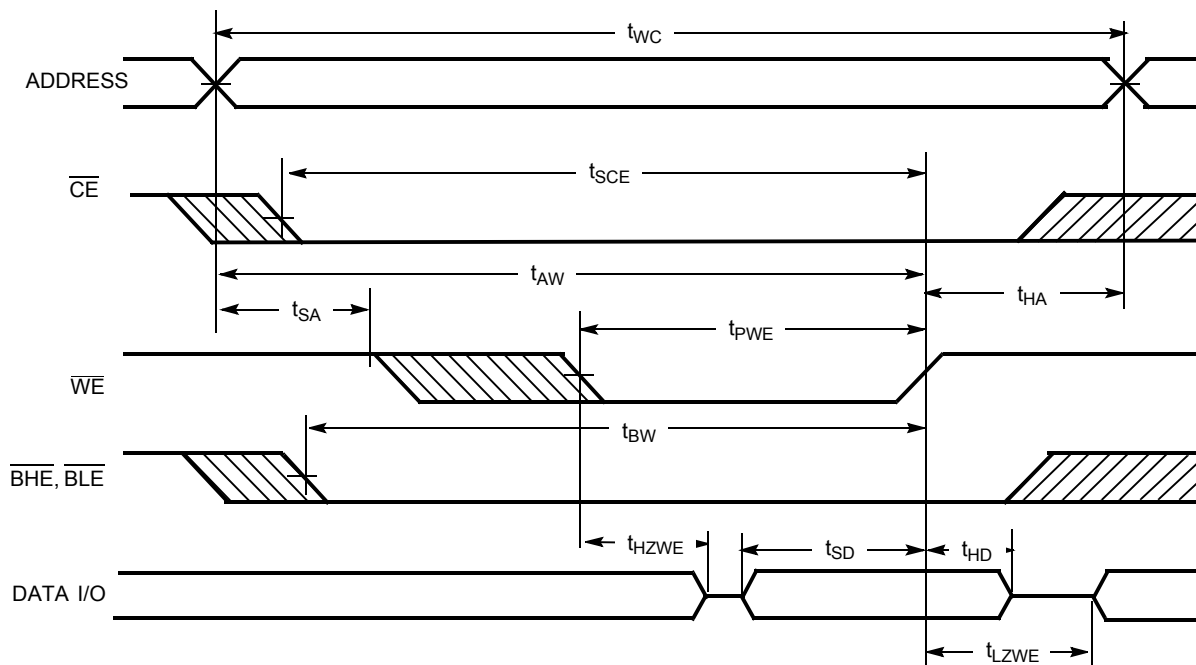


Notes

12. Data I/O is high impedance if $\overline{\text{OE}}$ or $\overline{\text{BHE}}$ and/or $\overline{\text{BLE}} = V_{\text{IH}}$.
13. If $\overline{\text{CE}}$ goes HIGH simultaneously with $\overline{\text{WE}}$ going HIGH, the output remains in a high-impedance state.

Switching Waveforms *(continued)*

Write Cycle No. 3 ($\overline{\text{WE}}$ Controlled, $\overline{\text{OE}}$ LOW)



Truth Table

CE	OE	WE	BLE	BHE	I/O ₁ –I/O ₈	I/O ₉ –I/O ₁₆	Mode	Power
H	X	X	X	X	High Z	High Z	Power-down	Standby (I_{SB})
L	L	H	L	L	Data out	Data out	Read—All bits	Active (I_{CC})
			L	H	Data out	High Z	Read—Lower bits only	Active (I_{CC})
			H	L	High Z	Data out	Read—Upper bits only	Active (I_{CC})
L	X	L	L	L	Data in	Data in	Write—All bits	Active (I_{CC})
			L	H	Data in	High Z	Write—Lower bits only	Active (I_{CC})
			H	L	High Z	Data in	Write—Upper bits only	Active (I_{CC})
L	H	H	X	X	High Z	High Z	Selected, outputs disabled	Active (I_{CC})
L	X	X	H	H	High Z	High Z	Selected, outputs disabled	Active (I_{CC})

Ordering Information

Speed (ns)	Ordering Code	Package Diagram	Package Type	Operating Range
15	CY7C1020CV33-15ZSX E	51-85087	44-pin TSOP Type II (Pb-free)	Automotive
	CY7C1020CV33-15ZSXET	51-85087	44-pin TSOP Type II (Pb-free)	Automotive

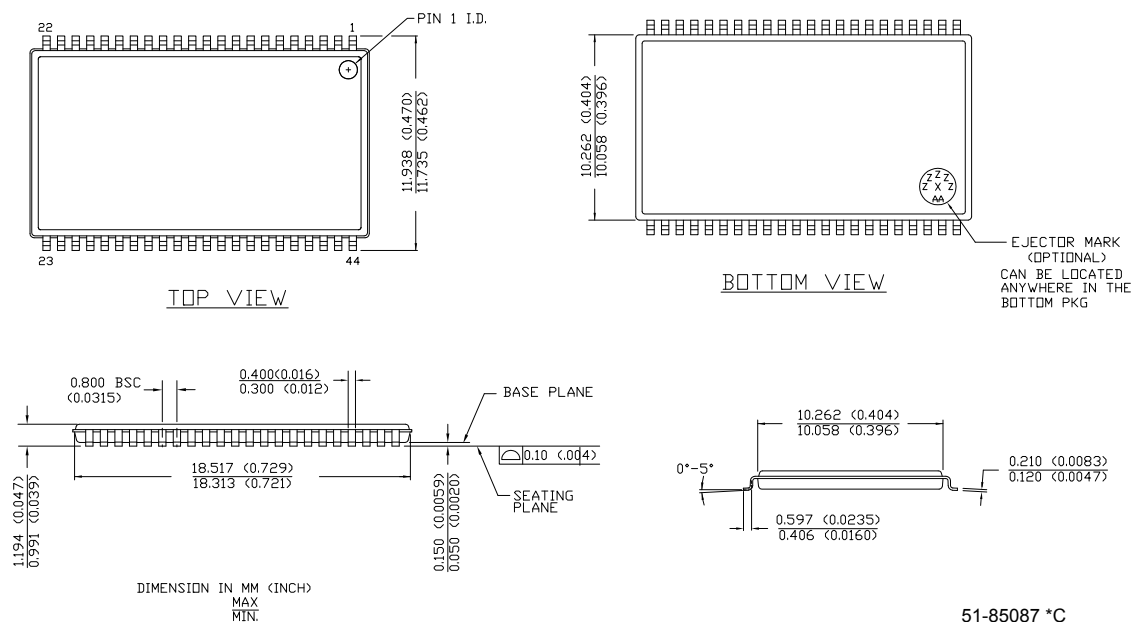
Ordering Code Definitions

CY7C 1020 C V33 - 15 ZSX E X

X = T or Blank
T = Tape and Reel; Blank = Tube
Temperature Range:
E = Automotive
Package Type:
ZSX = 44-pin TSOP Type II (Pb-free)
Speed Grade = 15 ns
V33 = 3.3 V
Process Technology = 0.16 μ m
1020 = Part Identifier
CY7C = Cypress SRAMs

Package Diagrams

Figure 1. 44-pin TSOP II, 51-85087



Acronyms

Acronym	Description
CMOS	complementary metal oxide semiconductor
CE	chip enable
I/O	input/output
OE	output enable
SRAM	static random access memory
TSOP	thin small-outline package
TTL	transistor-transistor logic
WE	write enable

Document Conventions

Units of Measure

Symbol	Unit of Measure
ns	nano seconds
V	Volts
μA	micro Amperes
mA	milli Amperes
mW	milli Watts
MHz	Mega Hertz
pF	pico Farad
°C	degree Celcius
W	Watts
%	percent

Document History Page

Document Title: CY7C1020CV33 512 K (32 K × 16) Static RAM Document Number: 38-05133				
REV.	ECN NO.	Issue Date	Orig. of Change	Description of Change
**	109428	12/16/01	HGK	New Data Sheet
*A	115045	05/30/02	HGK	I _{CC} and I _{SB1} data modified
*B	117615	08/14/02	DFP	Pin 1= NC Pin 18 = A4; remove SOJ package option; remove 8ns option.
*C	262949	See ECN	RKF	Added Automotive Specs to Data sheet
*D	334398	See ECN	SYT	Added Lead-Free Product Information
*E	493543	See ECN	NXR	Added note #1 on page #1 Changed the description of I _{IX} from Input Load Current to Input Leakage Current in DC Electrical Characteristics table Removed I _{OS} parameter from DC Electrical Characteristics table Updated Ordering Information Table
*F	2897691	03/23/2010	RAME	Updated Ordering Information Updated Package Diagram
*G	3057593	10/13/2010	PRAS	Updated Ordering Information and added Ordering Code Definitions .
*H	3100106	12/02/2010	PRAS	Added Acronyms and Units of Measure . Minor edits and updated in new template.

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